

REVISIONS				DOC. NO. SPC-F004 * Effective: 7/8/02 * DCP No: 1398						
DCP #	REV	DESCRIPTION	DRAWN	DATE	CHECKD	DATE	APPRVD	DATE		
1262	Α	RELEASED	НО	2/26/03	JWM	2/26/03	DJC	2/26/03		
1885	В	UPDATED TO ROHS COMPLIANCE	EO	02/03/06	НО	2/6/06	НО	2/6/06		

Description: A silicon NPN Darlington transistor in a TO-220 type case designed for general-purpose amplifier and low-speed switching applications.

Features:

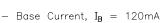
- High DC Current Gain
- Collector-Emitter Sustaining Voltage: V_{CEO(sus)} = 100V Min @ 100mA
- Monolithic Construction with Built-in Base-Emitter Shunt Resistors

Absolute Maximum Ratings:

- Collector-Emitter Voltage, $V_{CEO} = 100V$
- Collector-Base Voltage, $V_{CB} = 100V$ Emitter-Base Voltage, $V_{EB} = 5V$
- Collector Current, $I_{\mathbb{C}}$:

Continuous = 5A





- Total Power Dissipation ($T_C = +25^{\circ}C$), $P_D = 65W$

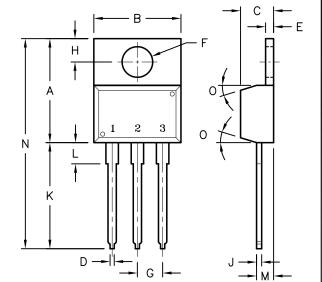
Derate above $+25^{\circ}C = 0.52W/^{\circ}C$

Total Power Dissipation ($T_A = +25^{\circ}C$), $P_D = 2W$

Derate above $+25^{\circ}C = 0.016W/^{\circ}C$

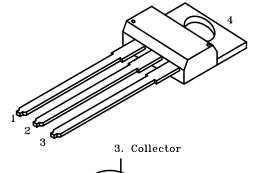
- Operating Junction Temperature Range, $T_J = -65^{\circ}$ to $+150^{\circ}$ C
- Storage Temperature Range, $T_{stg} = -65^{\circ}$ to $+150^{\circ}$ C Thermal Resistance, Junction-to-Case, $R_{thJC} = 1.92^{\circ}$ C/W
- Thermal Resistance, Junction-to-Ambient, R_{thJA} = 62.5°C/W

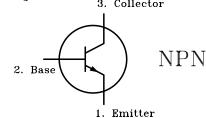




Electrical	Characteristics:	$(T_A$	=	+25°C	unless	otherwise	specified)	
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Symbol	Test Conditions	Min	Typ	Max	Unit						
V _{CEO(sus)}	$I_{C} = 100 \text{mA}, I_{B} = 0, \text{ (Note 1)}$	100	-	-	V						
I_{CEO}	$V_{CE} = 50V, I_{B} = 0$	_	1	0.5	mA						
I_{CBO}	$V_{CB} = 100V, I_{E} = 0$	_	_	0.2	mΑ						
I_{EBO}	$V_{BE} = 5V, I_{C} = 0$	_	-	2	mA						
ON Characteristics (Note 1)											
h _{FE}	$V_{CE} = 3V$, $I_{C} = 0.5A$	1000	-	-							
	$V_{CE} = 3V, I_{C} = 3A$	1000	_	-							
V _{CE(sat)}	$I_{\rm C}=3$ A, $I_{\rm B}=12$ mA	-	-	2	V						
	$I_{\rm C}=$ 5A, $I_{\rm B}=$ 20mA	-	-	4	٧						
V _{BE(on)}	$V_{CE} = 3V$, $I_{C} = 3A$	-	-	2.5	٧						
		•									
h _{fe}	$V_{CE} = 4V$, $I_{C} = 3A$, $f = 1MHz$	4	_	_							
Соь	$V_{CB} = 10V$, $I_{E} = 0$, $f = 0.1MHz$	_	-	200	рF						
	V _{CEO(sus)} I _{CEO} I _{CBO} I _{EBO} V _{CE(sat)} V _{BE(on)}	$\begin{split} I_{CBO} & V_{CB} = 100V, \ I_E = 0 \\ I_{EBO} & V_{BE} = 5V, \ I_C = 0 \\ \end{split}$ $\begin{aligned} h_{FE} & V_{CE} = 3V, \ I_C = 0.5A \\ V_{CE} = 3V, \ I_C = 3A \\ \end{split}$ $\begin{aligned} V_{CE(sot)} & I_C = 3A \\ I_C = 5A, \ I_B = 12mA \\ I_C = 5A, \ I_B = 20mA \\ \end{aligned}$ $\begin{aligned} V_{BE(on)} & V_{CE} = 3V, \ I_C = 3A \end{aligned}$ $\begin{aligned} h_{fe} & V_{CE} = 4V, \ I_C = 3A, \ f = 1MHz \end{aligned}$	$\begin{array}{c} V_{CEO(sus)} \ I_{C} = \ 100 \text{mA}, \ I_{B} = \ 0, \ (\text{Note 1}) \ \ 100 \\ I_{CEO} \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \$	$\begin{array}{c} V_{CEO(sus)} \ I_C \ = \ 100 \text{mA}, \ I_B \ = \ 0, \ (\text{Note 1}) \ \ 100 \ \ - \ \ \\ I_{CEO} \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \$	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$						





Note:

1. Pulse test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2%.

Dimensions	A	В	С	D	E	F	G	Н	J	K	L	M	N	0
Min.	14.42	9.63	3.56	_	1.15	3.75	2.29	2.54	_	12.70	2.80	2.03	_	7°
Max.	16.51	10.67	4.83	0.90	1.40	3.88	2.79	3.43	0.56	14.73	4.07	2.92	31.24	′

Pin Configuration

- 1. Base
- 2. Collector
- 3. Emitter
- 4. Collector

SPC-F004.DWG

TOLERANCES: DRAWN BY: DATE: DRAWING TITLE: Transistor, General Purpose, Bipolar, TO-220, NPN 2/26/03 HISHAM ODISH UNLESS OTHERWISE DWG. NO. ELECTRONIC FILE CHECKED BY: DATE: SIZE REV SPECIFIED, DIMENSIONS ARE JEFF MCVICKER 2/26/03 **TIP122** 35C0636.DWG В Α FOR REFERENCE DATE: APPROVED BY: PURPOSES ONLY, SCALE: NTS U.O.M.: Millimeters SHEET: 2/26/03 DANIEL CAREY

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